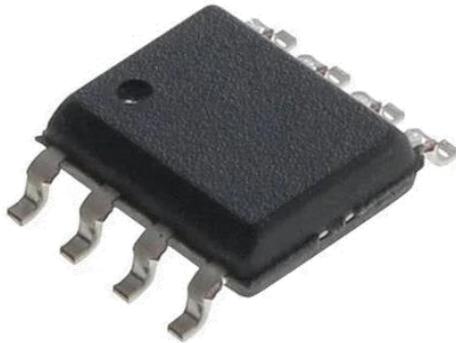


**4-LINE SMD TVS FOR ESD PROTECTION 5.0V - 24V**

**DESCRIPTION:**



ALPN054BT8 Thru ALPN244BT8 has 4-Line SMD TVS for ESD Protection 5.0V - 24V features 350 Watts ( $t_p = 8/20\mu s$ ) of power handling capability to accommodate the higher transient voltage levels which may be expected in extended common mode applications.

**FEATURES**

- 350 watts peak pulse power ( $t_p = 8/20\mu s$ )
- Protects four I/O lines (bidirectional).
- Working voltage: 5V, 8V, 12, 15V, 18V, 24V.
- Low leakage current.
- IEC 61000-4-2 (ESD)  $\pm 30kV$  (air),  $\pm 30kV$  (contact)
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- Suffix "-H" indicates Halogen-free part, ex. ALPN054BT8-H

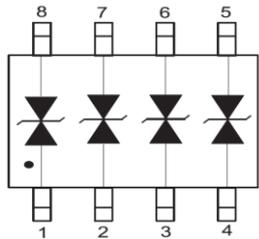
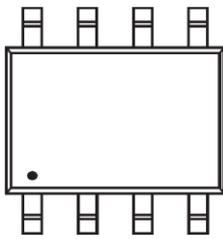
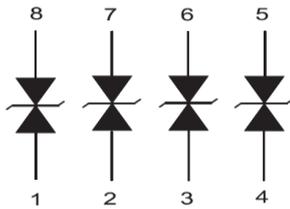
**APPLICATIONS**

- Cell phone handsets and accessories.
- Microprocessor based equipment.
- Personal digital assistants (PDA's).
- Notebooks, instrumentation.
- Portable instrumentation.

**MECHANICAL DATA**

- Molding compound flammability rating: UL 94V-0.
- Case: Molded plastic, SOP-08.
- Terminals: Plated terminals, solderable per MIL-STD-750, Method 2026.
- Weight: Approximately 0.18 gram.

**PINNING INFORMATION**

PIN CONFIGURATION	SIMPLIFIED OUTLINE	CIRCUIT DIAGRAM
		

**ELECTRICAL CHARACTERISTICS**
**ELECTRICAL CHARACTERISTICS (at T<sub>A</sub> = 25 °C unless otherwise noted)**

PARAMETER	SYMBOL	VALUES						UNIT
		ALPN054BT8	ALPN084BT8	ALPN124BT8	ALPN154BT8	ALPN184BT8	ALPN244BT8	
Reverse Stand-Off Voltage	V <sub>RWM</sub>	5	8	12	15	18	24	V
Reverse Leakage Current	I <sub>R</sub>	0.1	0.1	0.1	0.1	0.1	0.1	μA
Minimum Reverse Breakdown Voltage (@I <sub>T</sub> = 1mA)	V <sub>BR (Min)</sub>	6	9.2	13.3	16.7	20.4	26.7	V
Clamping Voltage (@I <sub>PP</sub> = 1A)	V <sub>C</sub>	10	13	18	24	29	35	V
Maximum Peak Pulse Current (8/20μs)	I <sub>PPM</sub>	22	15	10	7	6	5	A
Maximum Clamping Voltage (@I <sub>PPM</sub> )	V <sub>CM</sub>	16	20	25	30	35	42	V
Junction Capacitance	C <sub>T</sub>	90	75	50	40	30	25	pF

**Note:**

1. Non-repetitive current pulse 8/20 us exponential decay waveform according to IEC61000-4-5.

**ABSOLUTE MAXIMUM RATINGS**
**ABSOLUTE MAXIMUM RATINGS (at T<sub>A</sub> = 25 °C unless otherwise noted)**

PARAMETER	SYMBOL	VALUE	UNIT
IEC 61000-4-2 (ESD) Air Contact	V <sub>ESD</sub>	±30 ±30	kV
Peak pulse power (t <sub>p</sub> =8/20us waveform)	P <sub>PP</sub>	350	W
Lead Soldering Temperature	T <sub>L</sub>	260 (10 sec.)	°C
Operating Temperature	T <sub>OPT</sub>	+150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

TYPICAL DEVICE CHARACTERISTICS CURVES

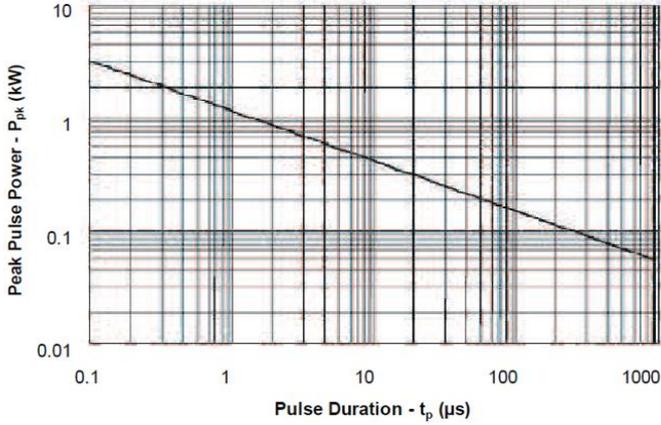


Fig1. Non-Repetitive Peak Pulse Power vs. Pulse Time

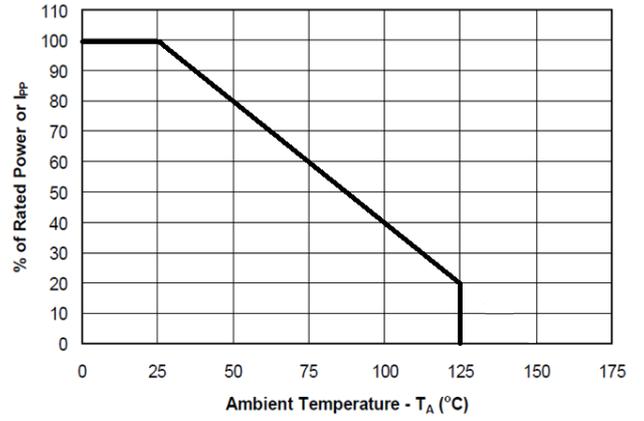


Fig2. Power Derating Curve

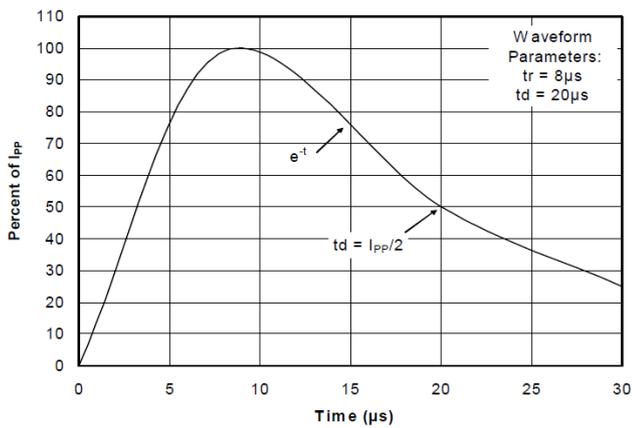
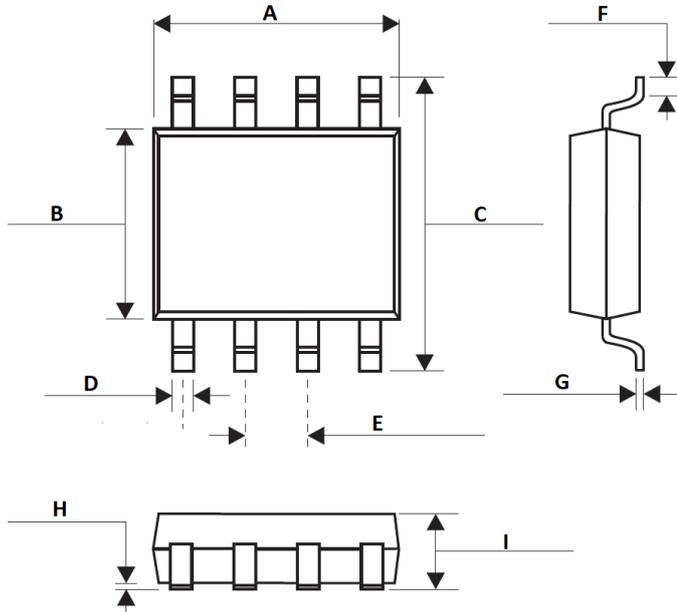


Fig3. Pulse Waveform

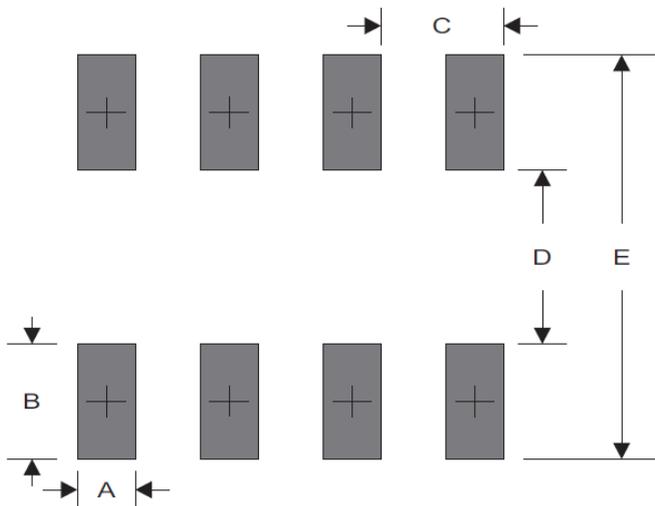
PACKAGE INFORMATION

SOP-08



OUTLINE DIMENSIONS				
SYMBOL	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.196
B	3.80	4.00	0.150	0.157
C	5.80	6.20	0.229	0.224
D	0.35	0.49	0.014	0.019
E	1.27 BSC.		0.050 BSC.	
F	0.40	1.25	0.016	0.049
G	0.18	0.25	0.007	0.009
H	0.05	0.25	0.004	0.008
I	1.35	1.75	0.054	0.068

PAD LAYOUT

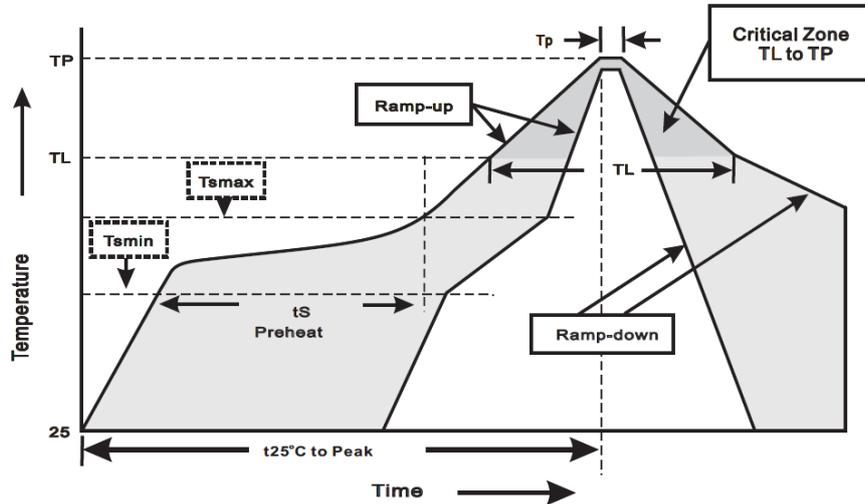


OUTLINE DIMENSIONS		
SYMBOL	MILLIMETERS	INCHES
A	0.60	0.024
B	1.10	0.043
C	0.95	0.037
D	2.50	0.098
E	1.40	0.055

**SOLDERING PARAMETERS**

**SUGGESTED THERMAL PROFILES FOR SOLDERING PROCESSES**

1. Storage environment: Temperature=5 °C~40 °C Humidity=55% ±25%
2. Reflow soldering of surface-mount devices



3. Reflow soldering

PROFILE FEATURE	SOLDERING CONDITION
Average ramp-up rate (TL to TP)	<3 °C/sec
Preheat	
- Temperature Min (T <sub>smin</sub> )	150 °C
- Temperature Max (T <sub>smax</sub> )	200 °C
- Time (min to max) (t <sub>s</sub> )	60 ~ 120 sec
T <sub>smax</sub> to TL	
- Ramp-upRate	<3 °C/sec
Time maintained above:	
- Temperature (TL)	217 °C
- Time(t <sub>L</sub> )	60 ~ 260 sec
Peak Temperature (TP)	255 °C-0/+5 °C
Time within 5 °C of actual Peak Temperature(t <sub>p</sub> )	10 ~ 30 sec
Ramp-down Rate	<6 °C/sec
Time 25 °C to Peak Temperature	<6 minutes



*beyond boundaries...*

## ALPN054BT8 Thru ALPN244BT8

SOP-08

### PRODUCT HIGH RELIABILITY TEST CAPABILITIES

ITEM	TEST CONDITIONS	STANDARD
Solder Resistance	At 260±5°C for 10±Sec.	MIL-STD-750D METHOD-2031
Solderability	At 245±5°C for 5 sec.	MIL-STD-202F METHOD-208
High Temperature Reverse Bias	$V_{BR} = V_{BR\ Min} * 80\%$ at $T_J=150^\circ\text{C}$ for 168 hrs.	MIL-STD-750D METHOD-1038
Pressure Cooker	15P <sub>SIG</sub> at $T_A=121^\circ\text{C}$ for 4Hrs	JESD22-A102
Temperature Cycling	-55°C to +125°C dwelled for 30min and transferred for 5min. total 10 cycles.	MIL-STD-750D METHOD-1051
Humidity	At $T_A=85^\circ\text{C}$ , RH=85% for 1000hrs.	MIL-STD-750D METHOD-1021
High Temperature Storage Life	At 150°C for 1000hrs.	MIL-STD-750D METHOD-1031



*beyond boundaries...*

**CUSTOMER NOTE:**

**DISCLAIMER**

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1. ALPINESEMI™ Semiconductor Devices are RoHS compliant and hence customers are requested to dispose as per the prevailing Environmental Legislation put forth in their specific country.
2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).



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